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Electrochemical Intercalation of Lithium Ions into NbSe₂ Nanosheets

Emily Hitz,^{†,⊥} Jiayu Wan,^{†,⊥} Anand Patel,[‡] Yue Xu,[†] Louisa Meshi,^{‡,§} Jiaqi Dai,[†] Yanan Chen,[†] Aijiang Lu,[†] Albert V. Davydov,^{*,‡} and Liangbing Hu^{*,†}

[†]Department of Materials Science and Engineering, University of Maryland, College Park, Maryland 20742, United States

[‡]Materials Science and Engineering Division, National Institute of Standards and Technology, Gaithersburg, Maryland 20878, United States

[§]Department of Materials Engineering, Ben Gurion University of the Negev, Beer Sheva 84105, Israel

ABSTRACT: Transition metal dichalcogenides (TMDCs) have been known for decades to have unique properties and recently attracted broad attention for their two-dimensional (2D) characteristics. NbSe₂ is a metallic TMDC that has been studied for its charge density wave transition behavior and superconductivity but is still largely unexplored for its potential use in engineered devices with applications in areas such as electronics, optics, and batteries. Thus, we successfully demonstrate and present evidence of lithium intercalation in NbSe₂ as a technique capable of modifying the material properties of NbSe₂ for further study. We demonstrate successful intercalation of Li ions into NbSe₂ and confirm



this result through X-ray diffraction, noting a unit cell size increase from 12.57 to 13.57 Å in the *c* lattice parameter of the NbSe₂ after intercalation. We also fabricate planar half-cell electrochemical devices using ultrathin NbSe₂ from platelets to observe evidence of Li-ion intercalation through an increase in the optical transmittance of the material in the visible range. Using 550 nm wavelength light, we observed an increase in optical transmittance of 26% during electrochemical intercalation.

KEYWORDS: electrochemical intercalation, niobium selenide, 2D materials, lithium, transparent electrodes

INTRODUCTION

A class of materials known as transition metal dichalcogenides (TMDCs) has been under renewed study due to recent advancements made in the area of layered two-dimensional (2D) materials, particularly with graphitic films for applications in electronics, optoelectronics, and electrochemical devices.^{1–5} As layered materials, TMDCs are known to exhibit a wide range of unique mechanical, electrical, and chemical properties that rival the advanced performance standards of other 2D materials such as graphene and BN.^{6–15} While TMDCs have been under study for decades, efforts within the scientific and engineering community to study the properties of these unique materials have strengthened again in large part due to recent advances in sample preparation and handling of 2D materials.^{16–20}

Many layered materials have been found to participate in a process called intercalation, which allows various molecules to be inserted and stored within a host crystal structure.^{21–27} These materials, especially in their 2D morphology, can provide energy storage capabilities²⁸ while also having the potential to meet concerns that are specific to the modern world, that is, their extraordinary optoelectronic properties^{29–31} and mechanical flexibility.^{32,33} Intercalation has been used as a technique to further enhance the properties of these materials for their optical, thermal, magnetic, and electronic behavior.^{34–41}

TMDCs are materials composed of stacks of atomically thin sheets having the chemical form MX_{2j} in which M is a transition metal (W, Mo, Nb) and X is a chalcogen (S, Se, Te). For NbSe₂, each constituent nanosheet has hexagonal structure in which one atomic layer of niobium is sandwiched between two atomic layers of selenium. Atoms are covalently bonded within the three-atom-thick layers, while van der Waals forces between the layers allow them to remain together. NbSe₂ has metallic conductivity at ambient conditions with superconducting and charge density wave transitions at low temperatures.^{42–44} Compared to its 2D "cousin" graphene, NbSe₂ is still largely unexplored for its chemical and physical properties.^{45,46}

In this work, we demonstrate a viable and accessible technique for modifying the properties of 2D NbSe₂ to allow for greater depth of study of the material's thermal, chemical, and optical behavior. Our approach relies upon electrochemical intercalation of an alkali metal ion, in this case lithium, into a layered material, which gives rise to specific optical and chemical changes.^{47,48} We provide evidence of these changes and characterization of the material system through high-resolution transmission electron microscopy (HRTEM),

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electrochemical investigations, optical microscopy, and X-ray diffraction (XRD) methods.

RESULTS AND DISCUSSION

For this investigation, we synthesized layered $NbSe_2$ in both powder and platelet form via the chemical vapor transport method. The $NbSe_2$ powder was used as the active material in coin cell electrodes for electrochemical testing (Figure 1a,b),



Figure 1. (a) A detailed look at the atomic structure of twodimensional nanosheets of 2H-NbSe₂, each composed of one atomic layer of Nb sandwiched between two layers of Se. (b) Through electrochemical cycling, lithium ions permeate the layered structure of NbSe₂, demonstrating its charge storage capability.

while single-crystal NbSe₂ platelets were used to fabricate planar devices for observation of the optical behavior of the material. A detailed enumeration of relevant techniques can be found in the Experimental Procedures section.

It is well-documented in previous research efforts on 2D materials that the electrochemical processes associated with lithium intercalation in TMDCs are often complex, involving both reversible and nonreversible reactions and having multiple lithiation/delithiation stages. With the likelihood of a complex system taken into consideration, our goal was to study the structural and compositional behavior of the electrochemical lithiation process in NbSe2. We first performed cycling and cyclic voltammetry (CV) electrochemical studies on coin cells (half cell with Li as counter electrode) containing an NbSe₂based cathode in the voltage range of 0-3 V, which was found to have many stages of lithiation reactions present. We exclude this regime from our focus of discussion. After further electrochemical studies, it was found that cycling the coin cells within the voltage range of 1-3 V allowed the system to stay within a simpler lithiation/delithiation regime. To

characterize the system of lithium intercalation in NbSe₂, we present data on the electrochemical behavior of coin cells cycled between 1 and 3 V with a current density of 50 mA/g. An electrochemical workstation (Biologic SP-150)⁴⁹ was used to acquire the charge-discharge voltage profile of the coin cells. The cells showed reasonably high specific capacity, as shown in the charge-discharge curves for the first three cycles (Figure 2a). The charge capacity of the cell was observed to be 372 mAh/g for the first cycle. On the second and third charge cycles, we observed a specific capacity of 342 mAh/g and 336 mAh/g, respectively. The discharge capacity of the cell exhibited a larger decrease in the capacitance after the first cycle than was observed correspondingly when charging the cell. During the first discharge cycle, a specific capacity of 534 mAh/g was observed. On the second and third discharge cycles, the specific capacity decreased to 347 mAh/g and 332 mAh/g, respectively. According to the reversible specific capacity of Li-NbSe₂ cycled from 1-3 V, the number of Li ions intercalated per NbSe₂ is calculated to be 3.48, corresponding to the formation of Li₃₄₈NbSe₂. Results give evidence of at least one nonreversible reaction occurring in the system at 1.22 V, which can also be seen in Figure 2, panel b in the CV curve for cycle 1. The cells otherwise demonstrate good reversibility after the first cycle. In Figure 2, panel b, CV curves for the first three cycles are shown, which confirm the voltage levels at which of the reactions present within the system occur. Reversible reactions are observed at 1.55 V, 1.99 V (cathodic), and 2.74 V (anodic).

While electrochemical studies allowed us to characterize the evolution of lithium intercalation in NbSe2, indexing of XRD peaks for discharged coin cell cathodes was crucial in our investigation of the structure and identity of the lithiated material. The results of this analysis can be seen in Figure 3, panels a and b. We first characterized the Li-intercalated-NbSe₂ system by performing XRD on the as-prepared NbSe₂-based coin cell electrodes to verify the composition and structure of the material. A peak identification analysis was performed on the spectra of the NbSe₂-based cathode prior to electrochemical discharge. Upon comparison with literature sources for peak information, 50,51 presence of hexagonal phase 2H-NbSe2 was detected. The material is known to be of the $P6_3mmc$ (194) space group, with the following lattice parameters: a = 3.44 Å and c = 12.55 Å. Experimentally, the lattice spacing of our material agreed well with the literature; through profile



Figure 2. Studies of electrochemical intercalation of Li ion in $NbSe_2$ -based electrodes. (a) Cycling behavior of the $NbSe_2$ -based cathode. (b) CV curves of the first three cycles of the $NbSe_2$ -based cathode. A voltage range of 1-3 V is selected to prevent solid–electrolyte interface formation.



Figure 3. (a) Full and (b) zoomed-in from 25° to 40° , XRD patterns of the NbSe₂-based cathode with carbon black additive and PVP polymer binder before and after electrochemical intercalation. After electrochemical discharge to 1 V, the presence of lithium via a change in the crystal unit cell size is evident, and after electrochemical discharge to 0 V, presence of Li and irreversible formation of a solid electrolyte interface layer is demonstrated.



Figure 4. (a) XRD from NbSe₂ platelets, (b) HRTEM image of NbSe₂ platelets sample, and (c) magnified HRTEM image of the same NbSe₂ platelet with crystallographic axes denoted; (d) electron diffraction taken at [0001] orientation of the NbSe₂ flake.

matching using a Le Bail fit with (TOPAS analysis software), the NbSe₂-based cathode sample was identified to have an *a* parameter of 3.4437(3) Å and a *c* parameter of 12.5668(3) Å. Elemental Cu in its cubic form was also detected. The presence of Cu in the X-ray diffractogram can be attributed to the copper foil current collector on which the slurry was deposited.

After electrochemical discharge from the intrinsic open circuit voltage of the cell to 1 V, we observed a preservation of the layered $NbSe_2$ structure, as indicated by the results of the peak identification. Because of the air-sensitivity of the discharged cathodes, Kapton tape was placed over the samples, which resulted in an observation of background diffraction from

10° to 30°. Profile matching using a Le Bail fit was performed on the XRD pattern for the cell discharged to 1 V. The results of this analysis showed that the unit cell size of the crystal increased upon discharge to 1 V, as a left-shift of the NbSe₂ peaks occurred. Most notably, the *c* parameter increased from 12.5668(3) Å before intercalation to 13.5702(5) Å, while the *a* parameter remained approximately unchanged at 3.4311(2) Å. An increase in the unit cell size in the direction of the *c* parameter corresponds to an increase in the interlayer spacing. We attribute this change in the interlayer spacing to the presence of lithium ions after intercalation.

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As shown in Figure 3, panels a and b, electrochemical discharge of a cell to 0 V resulted in a very different crystal structure than the discharge to 1 V. After peak identification, we observed a decreased relative intensity of NbSe₂ peaks to Cu peaks and an even larger left shift of NbSe₂ peaks for the region of 25° to 40° (Figure 3b). We attribute the left shift again to an increase in the *c*-axis to 13.57 Å due to Li intercalation in between the NbSe₂ layers and the lower relative intensity to the destruction of material during large amounts of lithiation.

In the previous section, we used NbSe₂ powder as active material to show that Li ion can electrochemically intercalate in the material. To further demonstrate Li-ion intercalation in 2D NbSe2 materials and the optical and structural changes that occur, we prepared NbSe2 by the chemical vapor transport method. Figure 4, panel a inset shows the truncated trapezoidshaped platelet with a [0001] basal facet is about 200 nm thick. The XRD peaks of the NbSe₂ platelet are at 14.46°, 28.56°, 43.32°, and 58.89°, which correspond to the (0002), (0004), (0006), and (0008) lattice planes of the 2H NbSe₂ ($P6_3/mmc$ (194); PDF#87-24015), with c lattice parameter of 12.570 Å. This XRD result clearly shows the NbSe₂ platelet we prepared is single crystalline. Transmission electron microscopy (TEM) was also utilized to characterize the NbSe₂ platelet. The stoichiometry was verified using standardless X-ray energy dispersive spectroscopy (EDS) in TEM. Figure 4, panel b shows the HRTEM image of the single crystalline NbSe₂. The dashed lines in the image indicate edges of areas with different thickness, which illustrate the layered nature of the material. Figure 4, panel c shows a magnified HRTEM image of the same sample. An interplanar distance of $d_{10.0} = 2.98 \pm 0.04$ Å is marked on the image. The selected area electron diffraction (SAED) pattern of NbSe₂ taken along [0001] direction is shown in Figure 4, panel d.

Planar batteries were built to study the optical properties of the $NbSe_2$ upon lithiation. As shown in a schematic image of the $NbSe_2$ planar battery in Figure 5, panel a, a thin flake of $NbSe_2$ and a small pellet of Li metal serve as working and



Figure 5. (a) Schematic of lithium intercalation in $NbSe_2$ with microbattery. (b) $NbSe_2$ flakes before electrochemical intercalation of lithium and (c) after lithium intercalation and electrochemical discharge to 0 V, both images taken under a wavelength of 550 nm. (d) Comparison of transmittance change observed for lithium intercalation at different wavelengths of light.

counter electrodes on a glass cover slide, while Cu current collectors are applied via thermal evaporation on the substrate. The NbSe₂ platelet is mechanically exfoliated and deposited on a clean glass cover slide prior to Cu deposition. Figure 5, panels b and c show the optical image of the NbSe₂ thin films by optical microscopy before and after Li intercalation at 550 nm wavelength light. The NbSe₂ flakes initially appear very dark in the micrograph, with an optical transmittance of 25%. After intercalation, the lithiated NbSe₂ flake shows a much lighter color in the image, with an optical transmittance of 51%. We also observed a wrinkle formation in the NbSe₂ thin film after lithiation, which arises from the volume expansion of the electrode material after Li-ion intercalation, typically seen in in battery electrodes.^{34,52–54} Figure 5, panel d shows the optical transmittance of the NbSe2 thin film before and after intercalation at wavelengths of 450 nm, 550 nm, and 750 nm, in which the transmittance increased from 24.3% to 49.7%, 27.5% to 54.5%, and 56.4% to 66.5%, respectively. Upon further analysis and computer simulation of intercalation, it was found that as the concentration of Li increased, the lattice paramater vertical to the layer surface increased remarkably. As a consequence, the overlap of the electron clouds between the layers decreased, and the band structure changed accordingly. The width of the energy bands decreased so that the interband transitions must take place at higher energies. With this, we saw a blue-shift in the overall dielectric function of the material, which corresponds to a dramatic change in transmittance. The two-fold transmittance increase as well as wrinkle formation confirm the successful intercalation of Li ion in the NbSe₂ thin film.

CONCLUSIONS

Through electrochemical and XRD studies, we provide evidence of lithium intercalation in 2H-NbSe₂ via an electrochemical method. In the electrochemical studies, we observed reversible and irreversible changes within a cycling voltage range of both 1-3 and 0-3 V. We confirm that the electrochemical lithiation mechanism in NbSe2 proceeds with Li intercalation between the NbSe2 layers rather than a conversion reaction commonly observed in other TMDCs (i.e., MoS_2) by XRD analysis. Though it can be readily calculated from the XRD pattern directly, we performed structure refinement to reveal an increase in the interplanar spacing by approximately 1 Å, which we claim is due to the presence of Li ion. From the cycling results, we confirmed that 3.48 Li ions are reversibly intercalated for every NbSe2 formula unit when discharged to 1 V. We support this claim with a corresponding result in the optical observation of electrochemical devices fabricated with thin flakes derived from NbSe2 in the platelet form. From in situ measurements of the change in flake transmittance during electrochemical discharge, we observed an increase in the transmittance. This result confirms successful intercalation of Li ions into NbSe2.

EXPERIMENTAL PROCEDURES

 $NbSe_2$ Powder Synthesis. Stoichiometric amounts of Nb and Se elemental powders were sealed in a quartz ampule under vacuum and annealed in a tube furnace at 850 °C for 84 h followed by cooling at 5 °C/min rate down to 400 °C and then being removed from the furnace. The reaction product was confirmed by XRD analysis to be pure polycrystalline NbSe₂.

NbSe₂ Platelet Growth. The NbSe₂ platelets were synthesized using the chemical vapor transport (CVT) method. A sample of

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0.9906 g of NbSe₂ polycrystalline powder was compressed into a pellet and sealed under vacuum in a quartz ampule with 66.5 mg of iodine added (equivalent to 4 mg/cm³ of I₂ concentration in the ampule), where iodine served as a transport agent in the CVT process. The ampule was heat treated in a horizontal tube furnace at 825 °C for 84 h, which resulted in the growth of single-crystalline platelets of NbSe₂, confirmed by XRD and TEM.

2D-Planar Device Fabrication. For the 2D planar devices, we used the single crystalline platelet form of NbSe₂. After preparing a glass cover slide by sonication in acetone and then methanol, we mounted it to a glass slide with Scotch tape. Via mechanical exfoliation, we prepared the sample on the glass slide and observed thin flakes of NbSe₂ under an optical microscope. The full device was then assembled by depositing copper current collectors that would form electrical connections between the flake and the rest of the device. The device was then finished by constructing a small chamber in which the LiPF₆ in EC/DEC (w/w = 1:1) electrolyte could be contained, filling the chamber in argon atmosphere, and sealing the device with another slide cover using epoxy glue.

Coin Cell Device Fabrication. Coin cells were fabricated using NbSe₂ powder as the active material of the cathode. A slurry mixture was first prepared with NbSe2 as the main component by adding acetylene black carbon as a conductive additive consistent with other electrochemical cell preparation techniques, and polyvinylpyrrolidone (PVP) as a binding agent. The slurry was combined in proportions of 7:2:1 NbSe₂/acetylene black/PVP by using water as the solvent. Once all components were evenly combined using a mortar and pestle, the mixture was deposited on clean copper foil using the doctor blade coating method and transferred to a vacuum oven at approximately 100 °C to allow the coating to dry completely. After, punches were used to prepare PVP separator and electrodes for coin cell assembly. In argon atmosphere, Li metal (Sigma-Aldrich), two sheets of PVP separator, lithium hexafluorophosphate solution in ethylene carbonate and diethyl carbonate (1 M LiPF₆ in EC/DEC w/w = 1:1) electrolyte, and the NbSe₂-based electrode were arranged in 20 mm diameter 304 stainless steel coin cell cases. The assembly was then crimped at approximately 1000 psi to form a functional coin cell device.

Preparation of NbSe₂ Cathodes for XRD Analysis. To perform XRD on the intercalated NbSe₂ coin cell devices, it was first necessary to remove the NbSe₂-containing electrodes from the coin cells. This task was made more challenging due to the sensitivity of the compounds to the atmosphere. We mitigated this concern by disassembling the coin cells inside a glovebox with argon atmosphere. The samples were mounted for XRD analysis while still inside the glovebox by applying Kapton polyimide film with silicone adhesive overtop each electrode. We intentionally prevented the tape from coming into contact with the sample directly, thus preventing contamination of the sample while still allowing an inert environment to be maintained during XRD analysis. XRD analysis was carried out on a D8 Advance with LynxEye and SolX capabilities.

Preparation of the NbSe₂ **Flakes for TEM Analysis.** For TEM investigation, the NbSe₂ flake was mounted using epoxy on a Cu TEM grid with an oval hole. Then, by using the "Scotch tape" method, the flake layers were removed to reduce the thickness to minimum (about 15 μ m). Final thinning was performed by Ar ions in a precision ion polishing system (PIPS, Gatan). TEM, EDS, and HRTEM studies were carried out on 300 kV Titan, FEI electron microscope.

AUTHOR INFORMATION

Corresponding Authors

*E-mail: binghu@umd.edu.

*E-mail: albert.davydov@nist.gov.

Author Contributions

[⊥]These authors contributed equally to this work.

Notes

The authors declare no competing financial interest.

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